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Received 27 Dec 2013 | Accepted 7 Jun 2014 | Published 11 Jul 2014

DOI: 10.1038/ncomms5353

OPEN

Photo-enhanced antinodal conductivity in the pseudogap state of high- T_c cuprates

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A major challenge in understanding the cuprate superconductors is to clarify the nature of the fundamental electronic correlations that lead to the pseudogap phenomenon. Here we use ultrashort light pulses to prepare a non-thermal distribution of excitations and capture novel properties that are hidden at equilibrium. Using a broadband (0.5–2 eV) probe, we are able to track the dynamics of the dielectric function and unveil an anomalous decrease in the scattering rate of the charge carriers in a pseudogap-like region of the temperature (T) and hole-doping (p) phase diagram. In this region, delimited by a well-defined $T^*_{neq}(p)$ line, the photoexcitation process triggers the evolution of antinodal excitations from gapped (localized) to delocalized quasiparticles characterized by a longer lifetime. The novel concept of photo-enhanced antinodal conductivity is naturally explained within the single-band Hubbard model, in which the short-range Coulomb repulsion leads to a **k**-space differentiation between nodal quasiparticles and antinodal excitations.

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uperconductivity in the cuprates takes place when charge carriers are injected into a charge-transfer insulator¹ in which the carriers are localized by the strong electronelectron interactions. This surprising phenomenon has motivated a remarkable effort to understand to what extent the electronelectron interactions determine the physical properties of cuprates when tuning these materials away from the insulating state by increasing the hole concentration *p* and the temperature T. The physics of superconducting cuprates is further complicated by an anisotropic gap (pseudogap) in the electronic density of states (DOS), which opens well above the superconducting critical temperature (T_c) at moderate doping and takes on maximal values close to the $\mathbf{k} = (\pm \pi, 0), (0, \pm \pi)$ regions (antinodes) of the Brillouin zone (BZ) (ref. 2). In the same region of the p-T phase diagram, different ordered phases have been observed. Such phases can be favoured by the reduced kinetic energy of the carriers and might be associated with a quantum critical point underneath the superconducting dome $T_{c}(p)^{3,4}$. Indeed, a wealth of different broken symmetries, such as unusual q = 0 magnetism⁵⁻⁷, charge-density waves (CDW)^{8,9}, stripes¹⁰, nematic and smectic phases¹¹⁻¹³, have been reported. The universal mechanism underlying the formation of the pseudogap continues to be the subject of intense research¹⁴, and the relation between the electronic interactions and the various ordering tendencies remains one of the major open questions.

A possible scenario that reconciles this phenomenology is that the pseudogap emerges as an inherent effect of the strong shortrange Coulomb repulsion, U, between two electrons occupying the same lattice site¹⁵. Considering the case of an isotropic Mott insulator, the U-driven suppression of charge fluctuations is expected to reduce the electron kinetic energy and render the electronic excitations increasingly localized in real space. Cluster generalization of dynamical mean-field theory (DMFT) calculations $^{16-18}$ suggests that the cuprates exhibit a similar Udriven reduction of kinetic energy that is, however, not uniform in momentum space. In the underdoped region, the antinodal excitations are indeed quasi-localized, with a T=0 divergent scattering rate that is reminiscent of the Mott insulator (see Fig. 1a), whose self-energy (SE) diverges at low frequency and decreases at finite temperature. In contrast, the nodal (N) excitations in the vicinity of $\mathbf{k} = (\pm \pi/2, \pm \pi/2)$ still retain the essential nature of the quasiparticles (QPs) at large hole concentrations, that is, a scattering rate that increases when external energy is provided (see Fig. 1b). The possible k-space differentiation between nodal QPs and antinodal excitations in the pseudogap phase has been hitherto elusive both to k-spaceintegrated equilibrium techniques, such as optical spectroscopy

and resistivity measurements, that are mostly sensitive to the properties of nodal QPs and to conventional angle-resolved photoemission spectroscopy (ARPES), which has limits in capturing small temperature- and k-dependent variations of the electronic scattering rate.

Here we adopt a non-equilibrium approach¹⁹ based on ultrashort light pulses (≈ 100 fs) used to artificially prepare the system in a non-thermal state with an excess of antinodal (AN) excitations²⁰. The key element of our experiment, which goes beyond single-colour pump-probe techniques 21-23, is that the dynamics of the optical properties are simultaneously probed over an unprecedentedly broad energy range (0.5-2 eV). This technique allows us to probe the damping of the infrared reflectivity plasma edge and to directly relate the transient reflectivity variation, $\delta R(\omega,t)$, to the instantaneous value of the optical scattering rate. From the outcome of time-resolved broadband spectroscopy, we infer that the transient nonthermal state created in the pseudogap phase is characterized by a scattering rate smaller than that at equilibrium. The emerging picture is that, on excitation, the localized antinodal states transiently evolve into more mobile states with a reduced scattering rate. This scenario is corroborated by DMFT calculations within the single-band Hubbard model and by time-resolved and ARPES (TR-ARPES) data in the pseudogap state. Finally, the generality of the concept of photo-enhanced antinodal conductivity in the pseudogap regime is demonstrated by combining the results obtained on different families of copper oxides (Bi- and Hg-based) in a single and universal phase diagram.

Results

Optical properties of cuprates. Non-equilibrium optical spectroscopy is emerging as a very effective tool to unravel the different degrees of freedom coupled to electrons in correlated materials^{19,24}. After the photoexcitation process, small variations of the equilibrium optical properties can be measured on a timescale faster than the recovery of the equilibrium QPs' distribution, the complete restoration of the (long-range) orders²⁵ and the heating of the phonons²⁶, thus unveiling an intriguing physics that cannot be accessed under equilibrium conditions. Single-colour time-resolved reflectivity measurements²¹⁻²³ have been applied in the past to study the pseudogap state, evidencing a characteristic dynamics proportional to the pseudogap amplitude $(|\Delta_{pg}|)$ and a change of sign of the photoinduced reflectivity variation at $T \approx T^*$. Nonetheless, the inherent lack of spectral information of single-colour techniques precluded the understanding of the origin of this pseudogap-related reflectivity

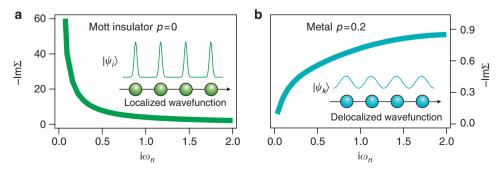


Figure 1 | **Electron scattering rate of correlated systems.** (**a**,**b**) The imaginary part of the electronic SE is calculated, as a function of the Matsubara frequency $\omega_n = (2n + 1)\pi k_B T$, by solving the single-band Hubbard model via single-site DMFT. The prototypical cases of the Mott insulator (p = 0) and metallic system (p = 0.2) are reported and contrasted. In the more realistic three-band Hubbard model, the same divergence of the SE is obtained as the charge-transfer insulating state is approached.

signal. Recent developments in ultrafast techniques now permit to overcome this limitation by probing the dynamics of the dielectric function over a broad frequency range. This paves the way to a quantitative modelling of the ultrafast optical response of the pseudogap phase.

To properly model the dynamics of the optical properties measured in non-equilibrium conditions, we start by introducing the basic elements that characterize the equilibrium reflectivity, $R_{eq}(\omega)$, of optimally doped Bi₂Sr₂Y_{0.08}Ca_{0.92}Cu₂O_{8+ δ} (OP-YBi2212, hole-doping p = 0.16, $T_c = 96$ K), shown in Fig. 2a. In the infrared region, the normal incidence $R_{eq}(\omega)$ is dominated by a metallic-like response, which is characterized by a broad edge at the dressed plasma frequency $\omega_p \approx 1.25$ eV. The infrared reflectivity of optimally and overdoped cuprates is well reproduced by the extended Drude model (EDM)^{27,28} in which a frequency-dependent optical scattering time, $\tau(\omega,T)$, accounts for all the processes that affect the QP lifetime, such as the electronic scattering with phonons, spin fluctuations or other bosons of electronic origin. Within the EDM, the optical scattering rate is connected to the single-particle SE by:

$$\gamma(\omega, T) = \frac{\hbar}{\tau(\omega, T)} = \operatorname{Im}\left\{\omega \left[\int_{-\infty}^{+\infty} \frac{f(\zeta, T) - f(\zeta + \omega, T)}{\omega + \sum^{*}(\zeta, T) - \sum(\zeta + \omega, T)} d\zeta\right]^{-1} - \omega\right\}$$
(1)

where *f* is the Fermi–Dirac distribution and $\Sigma(\zeta,T)$ and $\Sigma^*(\zeta,T)$ are the electron and hole **k**-space-averaged SEs. In Fig. 2a, we report the best fit of the EDM to the experimental $R_{eq}(\omega)$ of OP-YBi2212 at T = 100 K. In the calculation of the SE in equation (1), we use a recently developed model^{29–31} that takes into account a non-constant QPs' DOS, $\tilde{N}(\omega,T)$, characterized by a pseudogap width $\Delta_{pg} = 40$ meV (see Methods section). The **k**-spaceintegrated electronic DOS is recovered completely between Δ_{pg} and $2\Delta_{pg}$. The $\tilde{N}(\omega,T)$ extracted by optical spectroscopy (see Methods; Supplementary Notes 1 and 2; Supplementary Figs 1 and 2) is in agreement with the outcome of tunnelling experiments³². The quality of the fit to the optical properties (Fig. 2a) demonstrates that the EDM with a non-constant DOS is a very effective tool to extract the scattering properties of the charge carriers, at least for moderate hole-doping concentrations. The possible failure of the EDM model is expected for hole-doping concentrations smaller than those of the samples studied in this work. The interband transitions at $\hbar\omega > 1.5$ eV are accounted for by additional Lorentz oscillators at visible/ultraviolet frequencies. Focusing on the energy range that will be probed by the time-resolved experiment (0.5–2 eV), we note that $\tau(\omega)$ has almost approached the asymptotic value $\tau_{\infty} \approx 2$ fs (see inset of Fig. 2a). Therefore, we can safely assume that, in the 0.5–2 eV range, the damping of the reflectivity edge depends on the asymptotic value of the scattering rate, $\gamma_{\infty} = \hbar/\tau_{\infty}$.

Non-equilibrium optical spectroscopy. In the non-equilibrium optical spectroscopy, snapshots of the reflectivity edge of OP-YBi2212 are taken with 100 fs time resolution, as a function of the delay from the excitation with the 1.5 eV pump pulses. Considering that the temporal width of the probe pulses is much wider than the inherent scattering time of the charge carriers ($\tau_{\infty} \approx 2$ fs), we can assume that the electronic excitations have completely lost any coherence on a timescale faster than the observation time. Therefore, the transient optical properties can be rationalized by changing some effective parameters in the equilibrium reflectivity.

Notably, $R_{eq}(\omega, \gamma_{\infty})$ exhibits an isosbestic point (see Fig. 2a) at the frequency $\tilde{\omega} \sim 1.1 \text{ eV}$. At this frequency, the reflectivity is independent of γ_{∞} and, for small $\delta \gamma_{\infty}$ changes, it can be expanded as $\delta R(\omega, \gamma_{\infty}) = [\partial R(\omega)/\partial \gamma_{\infty}] \delta \gamma_{\infty}$, where $[\partial R(\omega)/\partial \gamma_{\infty}] > (<)0$ for $\omega > (<)\tilde{\omega}$ (see Supplementary Note 3; Supplementary Fig. 3). Therefore, the reflectivity variation, measured over a broad frequency range across $\tilde{\omega}$, can provide a direct information about the instantaneous value of the total scattering rate during the thermalization process of the photoinduced non-equilibrium QP population. In the bottom panel of Fig. 2a, we report the normalized reflectivity variation $\delta R/R(\omega)$, calculated from the equilibrium EDM model by assuming a positive (red line) or negative (blue line) variation of the total

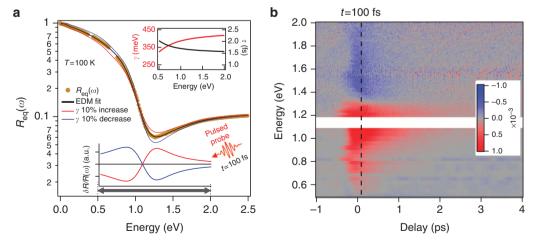


Figure 2 | Equilibrium and non-equilibrium optical spectroscopies. (a) The equilibrium reflectivity of an OP-YBi2212 sample, measured at T = 100 K in the 0-2.5 eV spectral range, is reported (yellow dots). The black line is the fit of the equilibrium EDM to the data. The red (blue) curve is the reflectivity obtained from the EDM, in which an increase (decrease) in the optical scattering rate is artificially introduced. The bottom panel displays the relative reflectivity variation in the case of an increase (red line) and a decrease (blue line) in the optical scattering rate. The optical scattering rate, $\gamma(\omega) = \hbar/\tau(\omega) = \hbar\omega_p^2/4\pi \text{Re}(1/\sigma_D(\omega))$, is reported in the inset. The grey bar highlights the spectral range probed by the non-equilibrium spectroscopy. (b) The relative reflectivity variation, $\delta R/R(\omega, t)$, is reported as a function of the probe photon energy ($\hbar\omega$) and pump-probe delay *t* in the form of an intensity map. The colour coding for $\delta R/R(\omega, t)$ is indicated by the colourscale.

scattering rate, γ_{∞} . The reflectivity variation associated with a change in γ_{∞} extends over a broad frequency range and it changes sign when crossing the isosbestic point $\tilde{\omega}$.

Figure 2b shows the frequency-resolved measurements on OP-YBi2212 at T = 100 K, as a function of the delay *t* from the pump pulse. The relative reflectivity variation $\delta R/R(\omega,t) = [R_{neq}(\omega,t) - R_{eq}(\omega)]/R_{eq}(\omega)$, where R_{neq} is the non-equilibrium reflectivity, is reported as a two-dimensional (2D) plot. The colour scale represents the magnitude of $\delta R/R(\omega,t)$ as a function of *t* and of the probe photon energy $\hbar \omega$. Soon after the excitation, $\delta R/R(\omega,t)$ is positive below $\tilde{\omega}$, whereas a negative signal is detected above $\tilde{\omega}$. When compared with the $\delta R/R(\omega)$ calculated for $\delta \gamma_{\infty} < 0$ (bottom panel of Fig. 2a), the measured $\delta R/R(\omega,t)$ suggests a transient decrease in the QP scattering rate soon after the excitation with the pump pulse.

To substantiate the possible transient variation of γ_{∞} , a differential model is used to quantitatively analyse the $\delta R/R(\omega,t)$ signal. This approach consists in finding out the minimal set of parameters that should be changed in the equilibrium dielectric function to satisfactorily reproduce the measured $\delta R/R(\omega,t)$ at a given time t. The main goal of this procedure is to disentangle the contributions of the genuine variation of γ_{∞} , from that of possible photoinduced band-structure modifications, such as the transient filling of the pseudogapped electronic states^{31,33}. In Fig. 3, we report a slice of $\delta R/R(\omega,t)$ (red dots) at fixed delay time, that is, t = 100 fs. $\delta R/R(\omega, t = 100$ fs) is qualitatively reproduced, over the whole probed frequency range, by modifying only two parameters in the equilibrium EDM, that is, $\tilde{N}(\omega,T)$ and γ_{∞} . In contrast, no change in the interband transitions and in the plasma frequency is required. This demonstrates that, in the probed spectral range, the $\delta R/R(\omega)$ signal is not significantly affected by the transient change in the electronic occupation at the pump energy scale or by other excitonic-like processes and that the density of the charge carriers is not significantly modified by the excitation process. Similarly, Fig. 3 also displays the contributions to the $\delta R/R(\omega, t = 100 \text{ fs})$ signal, as arising from the variation of $\tilde{N}(\omega,T)$ (green line) and γ_{∞} (blue line), separately. The central result is that a negative γ_{∞} variation is necessary to reproduce $\delta R/$ $R(\omega,t=100 \text{ fs})$. $\delta \gamma_{\infty} < 0$ corresponds to a narrowing of the reflectivity plasma edge around the isosbestic point at $\tilde{\omega}$ (see Fig. 2a), which is detected as a broad reflectivity variation changing from positive to negative when moving to high frequencies. Quantitatively, the relative variation $\delta \gamma_{\infty} / \gamma_{\infty} = -(1.2 \pm 0.4) \times 10^{-2}$ is extracted from the fitting procedure. For sake of clarity, we show in Fig. 3 the total $\delta R/$ $R(\omega)$ calculated (black dashed line) by constraining a positive $\delta \gamma_{\infty}/\gamma_{\infty} = +1.2 \times 10^{-2}$ variation (red dashed line). In this case, the main features of the measured $\delta R/R(\omega)$ cannot be, even qualitatively, reproduced. This demonstrates that, while the experimental uncertainties can affect the absolute value of $\delta \gamma_{\infty}/$ γ_{∞} , the transient photoinduced decrease in the scattering rate is a robust experimental fact that is unaffected by possible uncertainties, such as fluence fluctuations or changes in the pump-probe overlap.

The characteristic relaxation time t of the measured $\delta \gamma_{\infty}$ is obtained by fitting the function $\delta R/R(t) = \delta R/R(0)\exp(-t/t)$ to the time-resolved traces at fixed frequencies. In particular, we focus on the time traces at $\hbar\omega = 0.68$ and 1.55 eV, shown in Fig. 3b,c, for which the contribution from the $\tilde{N}(\omega,T)$ variation is negligible. The resulting value, $t = 600 \pm 50$ fs (see Supplementary Note 4; Supplementary Fig. 4), is of the same order as that of the time required for the complete heating of the lattice and for the recovery of the equilibrium QPs' population, as will be shown by the time-resolved photoemission measurements. Interestingly, on the picosecond timescale, the $\delta R/R(\omega)$ signal is qualitatively opposite to the signal at $t \approx 100$ fs, as shown by the time traces in

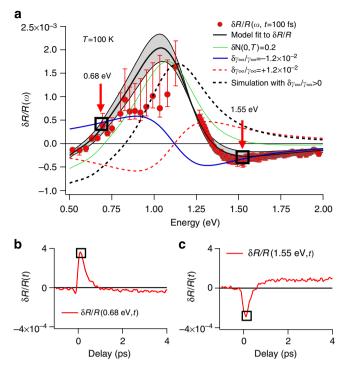


Figure 3 | Differential model for the non-equilibrium reflectivity. (a) The $\delta R/R(\omega, t = 100 \text{ fs})$, measured on the OP-YBi2212 sample at T = 100 K, is reported (red dots). The solid black line is the result of the fitting procedure of the differential model to $\delta R/R(\omega, t = 100 \text{ fs})$, in which the DOS $\tilde{N}(\omega,T)$ (see Methods) and γ_{∞} have been considered as free parameters. The contribution of each effect is shown separately: the green line represents the filling of the pseudogap DOS $(\delta \tilde{N} \equiv \tilde{N}_{neg}(0,T) - \tilde{N}_{eg}(0,T) =$ 0.2 ± 0.02), in agreement with recent time-resolved ARPES results³³; the blue line is related to the relative decrease of γ_{∞} . The dashed red line represents the $\delta R/R(\omega)$ due to an increase in the scattering rate. The dashed black line represents the calculation of $\delta R/R(\omega)$, assuming $\delta \tilde{N} = 0.2$ and $\delta\gamma_{\infty}/\gamma_{\infty}=+1.2\times10^{-2}.$ The red arrows highlight the probe energies at which the dynamics of the $\delta \gamma_{\infty}/\gamma_{\infty}$ variation is investigated. The measurements at $\omega < 1.2 \text{ eV}$ have been performed by tuning the probe wavelength through an optical parametric amplifier (see Methods). Therefore, each point at $\omega < 1.2 \text{ eV}$ belongs to a different time-domain measurement in which the uncertainty in the absolute amplitude (reported as a red bar) is larger than that of the measurements in the $\omega > 1.2 \text{ eV}$ frequency range. The error bars, accounting for the uncertainties in the pump fluence, size and spatial overlap with the probe beam, have been used as the weight for the fit. (b,c) Single-color time traces at photon energies $\hbar\omega = 0.68$ and 1.55 eV.

Fig. 3b,c. In particular, it changes from negative to positive as ω increases and crosses $\tilde{\omega}$. The $\delta R/R(\omega, t>1 \text{ ps})$ signal can be reproduced by a broadening of the reflectivity edge, equivalent to an increase in the scattering rate $(\delta \gamma_{\infty}/\gamma_{\infty} = 10^{-4})$, with a negligible contribution from the variation of $\tilde{N}(\omega,T)$. This γ_{∞} increase is compatible with a local effective heating $(\delta T=0.6 \text{ K})$ of the lattice, which can be estimated considering the pump fluence $(10 \,\mu\text{J cm}^{-2})$ and the specific heat of the sample (see Supplementary Note 5; Supplementary Fig. 5).

The transient decrease in the total electronic scattering rate, measured on the sub-picosecond timescale at T = 100 K, is a novel finding that contrasts both with the results²⁶ obtained well above the pseudogap temperature and with the behaviour expected for a metallic system. In the latter case, the scattering rate should increase as energy is delivered, either adiabatically or impulsively. Furthermore, as inferred from the $\delta R/R(\omega,t)$ measured in local quasi-equilibrium conditions (t > 1 ps), this anomalous $\delta \gamma_{\infty} < 0$ cannot originate from the partial quench of an order parameter or a temperature-induced decrease in the electron–boson coupling. In fact, the expected positive $\delta \gamma_{\infty} > 0$ is recovered at t > 1 ps, although on this timescale an increase in the effective electronic and bosonic temperatures and the related amplitude decrease in the possible order parameter are attained.

Non-equilibrium broadband optical spectroscopy crucially broadens the information that could be reached in the past by single-colour techniques. The quantitative modelling of the dynamics of the dielectric function in the 0.5-2 eV energy range demonstrates that, after the impulsive photoexcitation, the optimally doped YBi2212 sample at 100 K is driven into a nonequilibrium state, characterized by a scattering rate smaller than that at equilibrium ($\delta \gamma_{\infty} < 0$). In terms of the a.c. conductivity, this corresponds to a transient increase in the conductivity, once assumed a constant density of the charge carriers. The relaxation time of this photo-enhanced conductivity is $t = 600 \pm 50$ fs. On the picosecond timescale, the equilibrium distribution, dominated by nodal QPs, is recovered and a more conventional behaviour of the scattering rate ($\delta \gamma_{\infty} > 0$) is observed, in agreement with the outcomes of conventional equilibrium techniques, such as resistivity and optics^{34,35}.

The k-space-dependent non-equilibrium QP population. Since the energy scale of the pump photons (1.5 eV) is much larger than the thermal $(k_{\rm B}T \approx 10 \,{\rm meV})$ and the pseudogap $(\Delta_{\rm pg} \approx 40 \,{\rm meV})$ energy scales, the photoinduced QPs' distribution is expected to have no relation with the equilibrium one. The photoexcitation process can be roughly reduced to two main steps. In the first step, the pump pulse is absorbed creating electron-hole excitations extending from -1.5 to +1.5 eV across the Fermi energy ($E_{\rm F}$) and with a distribution that is regulated by the joint DOS of the photoexcitation process. In consequence of the extremely short scattering time of high-energy excitations ($\tau_{\infty} = \hbar/\gamma_{\infty} \approx 2$ fs), this photoexcited population undergoes a fast energy relaxation related to multiple scattering processes that lead to the creation of excitations at energies closer to $E_{\rm F}$. Considering the **k**-space-integrated DOS in the pseudogap state, a high density of excitations is expected to accumulate, within the pump-pulse duration

(0-100 fs), in the $\Delta_{pg} - 2\Delta_{pg}$ energy range from E_{F} . In the second and slower step, the subset of scattering processes that allow large momentum exchange, while preserving the energy conservation, leads to the recovery of a quasi-equilibrium distribution dominated by nodal QPs. Considering the phase-space constraints for these processes, the redistribution of excitations in the **k**-space is expected to be effective on the picosecond timescale.

To directly investigate the k-space electron distribution after the photoexcitation process with 1.5 eV ultrashort pulses, we apply a momentum-resolved technique. TR-ARPES (see Methods section) is applied to measure the transient occupation at different k-vectors^{36,37} along the Fermi arcs (see Fig. 4a) of a $Bi_2Sr_2CaCu_2O_{8+\delta}$ single crystal at T = 100 K. When considering the TR-ARPES spectra at fixed angles Φ from the antinodal direction (see Fig. 4a), the pump excitation results in a depletion of the filled states below $E_{\rm F}$ and a filling of the states above $E_{\rm F}^{36}$. In the following, we will focus on the integral (I) of the TR-ARPES spectra for $E > E_F$, which is proportional to the total excess of excitations in the empty states. Figure 4b reports the variation of I normalized to the intensity before the arrival of the pump pulse $(\Delta I_{\Phi}(t)/I_{\Phi})$ as a function of Φ . For each value of Φ , $\Delta I_{\Phi}(t)/I_{\Phi}$ is fitted by a single exponential decay of the form $\Delta I_{\Phi 0} \exp(-t/t_{\Phi})$, convoluted with a Gaussian function to account for the finite temporal resolution (\sim 100 fs). Figure 4c,d shows the **k**-dependent values of $\Delta I_{\Phi 0}$ and t_{Φ} extracted from the fitting procedure. Within the error bars, $\Delta I_{\Phi 0}$ increases by a factor 3 when moving from the node ($\Phi = 45^{\circ}$) towards the antinodal region of the BZ, indicating an effective photoinjection of AN excitations. This situation is dramatically different from that expected in equilibrium conditions, in which the number of excitations is governed solely by the Fermi-Dirac distribution at temperature T. In this case, the excitations' density should significantly decrease when approaching the AN region of the BZ, as a consequence of the gap $\Delta_{pg} \gg k_{B}T$ in the density of electronic states. Another notable result is that the relaxation time t_{Φ} is **k**-dependent, increasing from 300 to 800 fs when moving from the N to the AN region. These values are much larger than the total optical scattering time ($\tau_{\infty} = \hbar/\gamma_{\infty} \approx 2 \text{ fs}$), which demonstrates that the recovery of a quasi-equilibrium QPs' distribution is severely constrained, either by the phase space available for the scattering processes simultaneously conserving

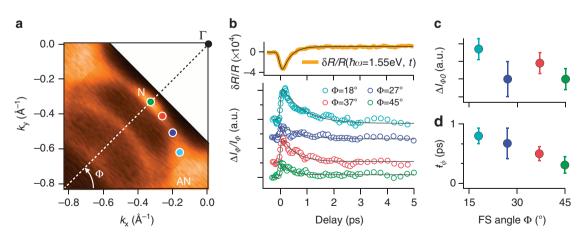


Figure 4 | Equilibrium and non-equilibrium photoemission. (a) The YBi2212 FS, measured by conventional ARPES at 100 K, is reported. The two FS replicas surrounding the main FS are due to surface reconstruction. The Γ point and the FS **k**-space regions where the TR-ARPES measurements have been performed are indicated by full dots. Φ is the FS angle from the antinode. (**b**) The normalized integrated variation of the TR-ARPES intensity above E_{F} , $\Delta I_{\Phi}(t)/I_{\Phi}$, is reported for different points along the Fermi arcs ($\Phi = 18^{\circ}$, 27° , 37° , 45°). Solid lines are the fit to the data with a single exponential decay, $\Delta I_{\Phi 0} \exp(-t/t)$. In the top panel, the $\delta R/R(t)$ trace at 1.55 eV is reported for comparison. (**c**,**d**) The maximum intensity variation, $\Delta I_{\Phi 0}$, and the decay time, t_{Φ} , of the non-equilibrium transient population measured by TR-ARPES are reported as a function of Φ . The error bars include the experimental uncertainty related to the possible alignment errors of the sample angle.

energy and momentum, or by some bottleneck effect related to the emission of gap-energy bosons during the relaxation of AN excitations.

TR-ARPES demonstrates that, soon after the excitation with 1.5 eV pump pulses, an excess number of low-energy electron excitations is accumulated in the antinodal region. Furthermore, the relaxation time of this non-equilibrium distribution is significantly k-dependent. Taken together, these results prove that this non-equilibrium electron distribution in the k-space cannot be described by a Fermi-Dirac distribution with a single effective electronic temperature that is evolving in time. At the simplest level, we can assume that the effective temperature increase in the excitations in the antinodal region is larger than that of the nodal QP population. Notably, the k-space-averaged time of the non-equilibrium relaxation distribution, $\langle t_{\Phi} \rangle = 550 \pm 200$ fs, is the same, within the error bars, as of the relaxation time of the transient $\delta \gamma_{\infty} < 0$ measured by nonequilibrium optical spectroscopy. This result demonstrates the direct relation between the creation of a non-thermal distribution with an excess of antinodal excitations and the transient decrease in the scattering rate measured by non-equilibrium optical spectroscopy.

 $T_{neq}^*(p)$ line emerging from non-equilibrium spectroscopy. The use of ultrashort light pulses to manipulate the equilibrium QP distribution is crucial to investigate the cuprate phase diagram from a perspective that was hitherto inaccessible. In this section, we report on the $T_{neq}^*(p)$ temperature below which the transient reduction of γ_{∞} is observed via non-equilibrium optical spectroscopy. As shown in Fig. 3a, for ω significantly above ω_p , the contribution to $\delta R/R(\omega,t)$ due to the modification of $\tilde{N}(\omega)$ is negligible. Therefore, single-colour pump-probe measurements at 1.55 eV probe photon energy contain the direct signature of the transient $\delta \gamma_{\infty} < 0$, in the form of a negative component^{21,22} with relaxation time $t = 600 \text{ fs}^{23}$. Figure 5a reports some of the single-colour time traces measured as a function of the temperature (from 300 to 20 K) for different hole concentrations. The negative component (blue colour) appears in the $\delta R/R(t)$ signal at

 $T_{neq}^* = 240 \pm 20 \text{ K}$ for p = 0.13 and at $T_{neq}^* = 165 \pm 20 \text{ K}$ for p = 0.16. Above p = 0.18, this negative $\delta R/R(t)$ signal is never detected on cooling the sample down to $T_{\rm c}$ (see Supplementary Notes 6 and 7; Supplementary Figs 6, 7 and 8). A similar behaviour is also found for underdoped HgBa₂CuO_{4+ δ} (Hg1201; see Supplementary Note 8; Supplementary Figs 9,10 and 11). Hg1201 is considered a nearly ideal single-layer cuprate and exhibits a maximal critical temperature close to that of doublelayer YBi2212^{38,39}. Collecting the results for the two materials on the same plot, we obtain a phase diagram that shows a universal behaviour for the properties of different copper-oxide-based superconductors having the same maximal critical temperature. Figure 5b shows that the p-T phase diagram of cuprates is dominated by an ubiquitous and sharp $T^*_{neq}(p)$ boundary. Below this line, the pump-induced non-thermal distribution of the charge carriers exhibits a scattering rate smaller than that at equilibrium. This pseudogap-like $T^*_{neq}(p)$ boundary meets the superconducting dome slightly above P = 0.18. Below T_c , the continuation of the $T_{neq}^{*}(p)$ line delimits two regions of the superconducting dome that exhibit opposite variation of the optical spectral weight of intra- and inter-band transitions^{24,40-42}, related to the crossing from a kinetic energy gain- to a potential energy gain-driven superconducting transition, consistent with predictions for the 2D Hubbard model⁴³.

Further insight into the $T_{neq}^{*}(p)$ line unveiled by nonequilibrium optical spectroscopy is provided by the comparison with the pseudogap temperature $T^{*}(p)$ estimated from complementary equilibrium techniques^{7,14,44,45} (elastic neutron scattering, resistivity and resonant ultrasound spectroscopy) and with the onset temperature of different ordered states^{46–48} (CDW, time-reversal symmetry-breaking states and fluctuating stripes). The picture sketched in Fig. 5c compares the main phenomenology on the most common materials with similar critical temperatures (Bi2212, Hg1201, YBCO). Remarkably, the $T_{neq}^{*}(p)$ line almost exactly coincides with the pseudogap line estimated by resistivity measurements⁴⁵ and ultrasound spectroscopy¹⁴ and with the onset of the newly-discovered q=0 exotic magnetic order^{7,44}. The appearance of ordered

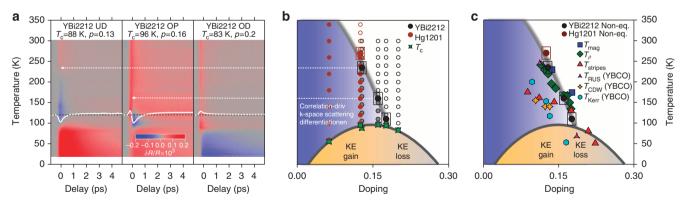


Figure 5 | The cuprate phase diagram from non-equilibrium spectroscopy. (a) The relative reflectivity variation $\delta R/R(t)$ measured at the probe energy of 1.55 eV is reported as a function of the temperature (from 300 to 20 K) for three YBi2212 samples with different hole concentrations: underdoped (UD, $T_c = 88$ K), optimally doped (OP, $T_c = 96$ K) and overdoped (OD, $T_c = 83$ K). The white lines are the $\delta R/R(t)$ time traces at 110 K. (b) The general phase diagram of cuprates, as unveiled by non-equilibrium reflectivity measurements, is sketched. The pseudogap boundary T^*_{neq} (grey curve) is determined reporting the temperature at which a negative component in the $\delta R/R(t)$ signal appears on YBi2212 (black dots) and underdoped Hg1201 (purple dots) samples with $T_c = 55$ and 95 K. The grey circles indicate some of the temperatures at which the $\delta R/R(t)$ data have been taken. The empty (full) circles correspond to a (non) zero negative signal in the $\delta R/R(t)$ time traces. The green markers denote the critical temperature T_c of the samples. (c) The $T^*_{neq}(p)$ temperatures extracted from time-resolved optical spectroscopy experiments are compared with the values of $T^*(p)$ extracted from resistivity⁴⁵ (green diamonds) and ultrasound spectroscopy¹⁴ (purple stars) on Bi2212 and YBCO and with the onset of the newly-discovered q = 0 exotic magnetic order^{7,44} (blue squares) on Bi2212 and time-reversal symmetry-breaking states in YBCO⁴⁶ (blue hexagons). KE, kinetic energy; non-eq., non-equilibrium.

states at $T < T^*$ is likely the consequence of the instability of the correlated pseudogap ground state on further cooling.

The antinodal scattering rate. The results reported in the previous sections suggest that the $T^*_{neq}(p)$ line delimits a region in which the AN states evolve into more metallic ones ($\delta \gamma_{\infty} < 0$) on photoexcitation with the pump pulses. The generality of the results obtained calls for a general model that accounts for the phase diagram unveiled by the non-equilibrium optical spectroscopy. Considering that the measured transient decrease in the carrier scattering rate is faster than the complete heating of the lattice, we focus on the minimal model that neglects electronphonon coupling and retains the genuine physics of correlations, that is, the 2D Hubbard Hamiltonian^{49,50}. To compute the temperature-dependent SE in different positions of the BZ, we use the dynamical cluster approximation, a cluster extension of DMFT that captures the k-space differentiation of the electronic properties17 between different regions of the BZ (see Methods section). Furthermore, long-range correlations are neglected to focus on the intrinsic effect of short-range correlations inside the chosen four-site cluster (see Methods section). At this stage, the increase in energy related to the pump excitation is mimicked by selectively increasing the effective temperature of the nodal and antinodal SEs.

The FS of a lightly doped system is reported in Fig. 6a and exhibits a progressive smearing when moving from the nodes to

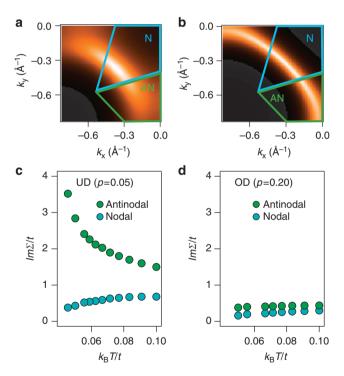


Figure 6 | The single-band Hubbard model and cluster-DMFT (CDMFT). (**a**,**b**) The FS reconstructed from CDMFT, for an UD (p = 0.05) and an OD (p = 0.2) sample, are reported. (**c**,**d**) The imaginary parts of the electronic SE, calculated through CDMFT as a function of the temperature, are reported for the UD and the OD samples, respectively. The effective temperature is expressed in units of the nearest-neighbor hopping *t*. Assuming a reasonable value t = 0.3 eV, kT/t = 0.1 corresponds to T = 350 K. The values of the parameters used in the calculations are U = 9t and t' = -0.25t. The imaginary parts of the SEs are calculated using dynamical cluster approximation (see ref. 4 and Methods section) and four equal-area partitions of the BZ. Following ref. 4, the nodal and antinodal SEs are calculated in the regions centred in **k** = (0,0) (N) and **k** = ($\pm \pi$,0), (0, $\pm \pi$) (AN), as shown in **a** and **b**.

the antinodes. This result is qualitatively in agreement with the FS experimentally measured by conventional ARPES in prototypical cuprates (compared with the ARPES data on optimally doped $Bi_2Sr_2Y_{0.08}Ca_{0.92}Cu_2O_{8+\delta}$ at 100 K reported in Fig. 4a). The smearing of the FS at antinodes reflects a strong dichotomy between the scattering rate of nodal and antinodal excitations that can be captured by plotting the imaginary parts of the calculated SE, that is, the inverse QP lifetime, as a function of the effective temperature (see Fig. 6c). In contrast to nodal QPs, whose scattering rate increases with temperature, the scattering rate of antinodal excitations exhibits a completely different evolution, decreasing as the effective temperature rises. This anomalous behaviour is related to the localized and gapped character of the antinodal fundamental excitations that experience very strong electronic interactions at low temperatures. The concept of delocalized QPs, characterized by a smaller scattering rate, is progressively recovered when the temperature increases. This striking dichotomy of the nature of the elementary excitations in the k-space is the consequence of a momentum-space selective opening of a correlation-driven gap, which eventually evolves into the full Mott gap at p = 0. The same physics has been previously identified in calculations based on similar approaches (also using larger clusters to achieve a better momentum resolution)^{16-18,51}. When the hole doping is increased (see Fig. 6b,d), the k-space differentiation of N-AN fundamental excitations is washed out and a more conventional metallic behaviour is recovered. In this case, the delocalized QPs exhibit a gapless energy spectrum and a scattering rate that is proportional to a power function of the temperature over the entire BZ.

DMFT calculations thus confirm an intrinsic *U*-driven momentum-space differentiation of the electronic properties of cuprates at finite hole concentrations and temperatures. The nature of the AN states is similar to that of a Mott insulator in the sense that the scattering rate of AN states decreases when the internal energy of the system is increased.

Discussion

Wrapping up the experimental outcomes collected in this work, we can gain a novel insight into the pseudogap physics of high-T_c cuprates. Time-resolved optical spectroscopy demonstrates that, on excitation with 1.5 eV pump pulses, the optical properties of cuprates transiently evolve into those of a more conductive system ($\delta \gamma_{\infty} < 0$). TR-ARPES shows that the **k**-space distribution of the electron excitations created by the pump pulse is characterized by an excess of AN electrons. Finally, the reported observation of a transient enhancement of the conductivity unveils a universal and sharp pseudogap-like $T^*_{neq}(p)$ boundary in the p-T phase diagram. All these results cannot be rationalized in terms of the simple consequence of an anisotropic scattering of QPs with bosonic fluctuations, such as antiferromagnetic spin fluctuations. Although antiferromagnetic correlations may strongly influence the dynamics of AN excitations, the energy provided by the pump pulse should necessarily result in an increase in the boson density, leading to an increase in the scattering rate for all the timescales. Furthermore, the transient decrease in the scattering rate on the sub-picosecond timescale cannot be related to the presence of incipient charge orders, such as CDW, which are quenched by the pump pulse. The picosecond dynamics of conventional CDW has been widely studied in weakly correlated $(U \approx 0)$ materials^{25,52}. After the impulsive excitation, the characteristic timescale for the CDW recovery is on the order of several picoseconds, that is, much longer than the transient $\delta \gamma_{\infty} < 0$ measured in our work. Even assuming a purely electronic (and faster) density wave mechanism in cuprates, the photoinduced decrease in the scattering rate should monotonically decrease eventually approaching a zero value. This is in contrast with the experimental observation of a transition from $\delta \gamma_{\infty} < 0$ to $\delta \gamma_{\infty} > 0$ on the picosecond timescale.

On the other hand, the Hubbard model provides a minimal framework for the interpretation of the pseudogap region of cuprates as unveiled by time-resolved spectroscopies. The pump pulse provides energy to the system in a non-thermal way, which can be schematized as a larger increase in the effective temperature of AN excitations as compared with that of nodal QPs. The transient decrease in the scattering rate ($\delta \gamma_{\infty} < 0$) is thus related to the evolution of AN excitations from Mott-like gapped excitations to delocalized QPs with a longer lifetime. On the picosecond timescale, the equilibrium electronic distribution is recovered and the expected $\delta \gamma_{\infty} > 0$ is measured. Although this picture does not exhaust all the properties of the pseudogap, it captures a key element of the universal and fundamental nature of the antinodal states, providing a backbone for more realistic multi-band descriptions³ that could give rise to a brokensymmetry state originating from a quantum phase transition⁴ at T = 0. Furthermore, the short-range Coulomb repulsion induces a suppression of the charge fluctuations below the $T_{neq}^{*}(p)$ line that is opposite to the effect of temperature. Therefore, the region of the cuprate phase diagram delimited by $T^*_{neq}(p)$ is intrinsically prone to bulk^{53,54} and surface^{55,56} phase-separated instabilities, whose nature depends on the details of the Fermi surface (FS) of the particular system considered. Interestingly, the region of the cuprate phase diagram in which the optical photoexcitation creates a non-equilibrium state with longer lifetime closely corresponds to that in which the possibility of creating a transient superconductive state by tetrahertz excitation has been recently discussed^{57,58}. These findings suggest a general tendency of copper oxides to develop, when photoexcited, a transient nonequilibrium state that is more conductive than the equilibrium phase.

Methods

Samples. The Y-substituted Bi2212 single crystals were grown in an image furnace by the travelling solvent floating-zone technique with a non-zero Y content to maximize T_c^{38} . The underdoped samples were annealed at 550 °C for 12 days in a vacuum-sealed glass ampoule with copper metal inside. The overdoped samples were annealed in a quartz test tube under pure oxygen flow at 500 °C for 7 days. To avoid damage of the surfaces, the crystals were embedded in Bi₂Sr₂CaCu₂O_{8+ δ} powder during the annealing procedure. In both cases, the quartz tube was quenched into ice-water bath after annealing to preserve the oxygen content at annealing temperature.

The fJg1201 single crystals were grown using a flux method, characterized and heat treated to the desired doping level³⁹. The crystal surface is oriented along the *ab*-plane with a dimension of about 1 mm². Hg1201 samples are hygroscopic. Therefore, the last stage of the preparation of the sample surface is done under a continuous flow of nitrogen, on which the sample is transferred to the high-vacuum chamber (10^{-7} mbar) of the cryostat within a few minutes. Before each measurement, the surface is carefully checked for any evidence of oxidation.

Optical spectroscopy. The *ab*-plane dielectric function at equilibrium of the YBi2212 samples has been measured using conventional spectroscopic ellipsometry⁵⁹. The dielectric function has been obtained by applying the Kramers– Kronig relations to the reflectivity for $50 < \omega/2\pi c < 6,000 \text{ cm}^{-1}$ and directly from ellipsometry for $1,500 < \omega/2\pi c < 36,000 \text{ cm}^{-1}$.

The $\delta R/R(\omega,t)$ data presented in Fig. 2 have been acquired combining two complementary techniques⁶⁰: (i) a pump supercontinuum-probe setup⁶¹, based on the white light generated in a photonic crystal fibre seeded by a Ti:sapphire cavity-dumped oscillator, to explore the visible–near infrared range of the spectrum (1.1–2 eV); (ii) a pump tunable-probe setup, based on an optical parametric amplifier seeded by a regenerative amplifier, to extend measurements in the infrared spectral region (0.5–1.1 eV). In both cases, the laser systems operate at 250 kHz repetition rate. The pump fluence is set to $10 \pm 2 \,\mu$ J cm⁻² for spectroscopic measurements. Single-colour measurements ($\hbar \omega = 1.55 \,\text{eV}$), presented in Fig. 5, have been performed directly using the output of a cavity-dumped Ti:sapphire oscillator. The high-frequency modulation of the pump beam, combined with a fast scan of the pump-probe delay and lock-in acquisition, ensures a high signal-to-noise ratio (~10⁶) and fast acquisition times, necessary to study the evolution of the time-resolved optical properties as a function of the temperature. Single-colour

measurements have been performed with a pump fluence ranging from 3 to $30 \,\mu J \, cm^{-2}$. In all experiments, the pump photon energy is 1.55 eV. Samples are mounted on the cold finger of a closed-cycle cryostat. The temperature of the sample is stabilized within $\pm 0.5 \, K$.

The EDM with a non-constant DOS. In the EDM, the scattering processes are effectively accounted for by a temperature- and frequency-dependent scattering rate $\gamma(\omega, T)$, which is often expressed through the so-called memory function, $M(\omega, T)$. The dielectric function resulting from the EDM is:

$$\varepsilon_{\rm D}(\omega,T) = 1 - \frac{\omega_{\rm p}^2}{\omega(\omega + M(\omega,T))}$$

In the conventional formulation of the EDM (for more details, see refs 28,31), the calculation of the SE $\Sigma(\omega, T)$ is based on the assumption of a constant DOS at the Fermi level. This approximation is valid at T = 300 K in optimally and overdoped systems, but fails as the temperature and the doping decrease and a pseudogap opens in the electronic DOS. A further evolution of the EDM, accounting for a non-constant electronic DOS, has been recently developed²⁹, and has been used to analyse spectroscopic data at equilibrium³⁰. Within this model, the imaginary part of the electronic SE is given by:

$$\begin{split} \sum_2 \left(\omega, T \right) &= -\pi \int_0^\infty \prod (\Omega) \{ \tilde{N}(\omega + \Omega, T) [n(\Omega, T) + f(\omega + \Omega, T)] \\ &+ \tilde{N}(\omega - \Omega, T) [1 + n(\Omega, T) - f(\omega - \Omega, T)] \} \mathrm{d}\Omega \end{split}$$

where *n* and *f* are the Bose–Einstein and Fermi–Dirac distribution functions, respectively; $\prod (\Omega)$ is the Bosonic function; and $\tilde{N}(\omega,T)$ is the normalized DOS. The real part of the SE, $\Sigma_1(\omega,T)$, can be calculated by using the Kramers–Kronig relations.

The normalized DOS $\tilde{N}(\omega, T)$ is modelled by³⁰:

$$\tilde{N}(\omega,T) = \begin{cases} \tilde{N}(0,T) + \left[1 - \tilde{N}(0,T)\right] \left(\omega/\Delta_{\text{pg}}\right)^2 & |\omega| \le \Delta_{\text{pg}} \\ 1 + 2/3 \left[1 - \tilde{N}(0,T)\right] & |\omega| \in \left(\Delta_{\text{pg}}, 2\Delta_{\text{pg}}\right) \\ 1 & |\omega| \ge 2\Delta_{\text{pg}} \end{cases}$$

Where $\Delta_{\rm pg}$ represents the (pseudo)gap width, while the normalized DOS at $E_{\rm F}$, that is, $\tilde{N}(0,T)$, represents the gap filling. The $\prod(\Omega)$ function is extracted by fitting the EDM to the normal state optical properties²⁶. $\prod(\Omega)$ is characterized by a low-energy part (up to 40 meV), a peak centred at ~60 meV and a broad continuum extending up to 350 meV.

The analysis of the time- and frequency-resolved data is performed by modelling the non-equilibrium dielectric function $(e_{neq}(\omega))$ and calculating the reflectivity variation through the expression: $\delta R/R(\omega,t) = [R_{neq}(\omega,t) - R_{eq}(\omega)]/R_{eq}(\omega)$, where the normal incidence reflectivities are calculated as: $R_{eq}(\omega) = [[1 - \sqrt{e_{eq}}(\omega)]/[1 + \sqrt{e_{eq}}(\omega)]]^2$ and $R_{neq}(\omega) = [[1 - \sqrt{e_{eq}}(\omega)]/[1 + \sqrt{e_{neq}}(\omega)]]^2$. The role of the finite penetration depth of the pump pulse $(d_{pu} = 160 \text{ nm} \text{ (m)})$

The role of the finite penetration depth of the pump pulse $(d_{pu} = 160 \text{ nm } @$ 1.55 eV) is accounted for by numerically calculating $\delta R/R(\omega)$ through a transfer matrix method, when a graded index of the variation of the refractive index *n* with exponential profile along the direction *z* perpendicular to the surface, that is, $\delta n = \delta n_0 \exp(-z/d_{pu})$, is assumed.

Photoemission spectroscopy. The FS of YBi2212 reported in Fig. 4a has been measured by ARPES in equilibrium conditions. ARPES has been performed with 21.2 eV linearly polarized photons (He- α line from a SPECS UVS300 mono-chromatized lamp) and a SPECS Phoibos 150 hemispherical analyzer. Energy and angular resolutions were set to 30 meV and 0.2°. The Bi2212 samples studied by TR-ARPES are nearly optimally doped single crystals with a transition temperature $T_c = 88$ K. The samples have been excited by 55 fs laser pulses with a photon energy of 1.55 eV at 300 kHz repetition rate, at an absorbed fluence of $35 \,\mu$ J cm⁻². The transient electron distribution was probed by time-delayed 80 fs, 6 eV laser pulses, photoemitting electrons, which were detected by a time-of-flight spectrometer. The energy resolution was 50 meV, the momentum resolution 0.05 Å⁻¹ and the time resolution <100 fs.

Cluster-DMFT and the Hubbard model. The Hubbard Hamiltonian^{49,50} is given by:

$$\hat{H} = -\sum_{i,j,\sigma} \left(t_{i,j} \hat{c}_{i\sigma}^{\dagger} \hat{c}_{j\sigma} + \text{c.c.} \right) + U \sum_{i} \hat{n}_{i,\uparrow} \hat{n}_{i,\downarrow} - \mu \sum_{i} \hat{n}_{i,\uparrow} \hat{n}_{i,\downarrow}$$

where $\hat{c}_{i\sigma}^{\dagger}(\hat{c}_{i\sigma})$ creates (annihilates) an electron with spin σ on the *i* (*j*) site, $\hat{n}_{i,\sigma} =$

 $\hat{c}_{i\sigma}^{\dagger}\hat{c}_{i\sigma}$ is the number operator, t_{ij} the hopping amplitude to nearest and next-nearest neighbours, U the Coulomb repulsion between two electrons occupying the same lattice site and μ is the chemical potential that controls the total number of electrons $n = \sum_{i\sigma} \langle \hat{n}_{i,\sigma} \rangle / N$ in the N sites.

The Hubbard model has been studied by means of a Cluster-DMFT that maps the full lattice model onto a finite small cluster (here a four-site cluster) embedded in an effective medium that is self-consistently determined as in standard meanfield theory. The method therefore fully accounts for the short-range quantum correlations inside the cluster. It has been shown by various authors that different implementations of this approach provide qualitatively similar results and reproduce the main features of the phase diagram of the cuprates, including the d-wave superconducting state and the pseudogap region that we discuss in the present paper. The calculations of this paper use the dynamical cluster approximation⁶² prescription and the 4* patching of the BZ introduced in¹⁷ and have been performed using finite-temperature exact diagonalization⁶³ to solve the self-consistent cluster problem using eight energy levels in the bath as in several previous calculations. The finite-temperature version of the exact diagonalization has been implemented as discussed in ref. 17 including typically 40 states in the low-temperature expansion of the observables.

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Acknowledgements

We thank D. Fausti, G. Zgrablic, G. Sordi, E. Gull, P. Werner, A. Avella, M. Fabrizio, A. Cavalleri, D. Manske, G. Ghiringhelli, B. Keimer, D. Mihailovic for the useful discussions and comments and for their support. The research activities of C.G., S.D.C., N.M., S.M., F.B., G.F., M.C., F.P. and U.B. have received funding from the European Union, Seventh Framework Programme (FP7 2007-2013), under Grant No. 280555 (GO FAST). F.C., G.C., and F.P. acknowledge the support of the Italian Ministry of University and Research under Grant No. FIRB-RBAP045JF2 and FIRB-RBAP06AWK3. M.C. is financed by European Research Council through FP7/ERC Starting Grant SUPERBAD, Grant Agreement 240524. L. R. and U. B. acknowledge support by the Mercator Research Center Ruhr (MERCUR). The YBi2212 crystal growth work was performed in M.G.'s prior laboratory at Stanford University, Stanford, CA 94305, USA, and supported by DOE-BES. The Hg1201 crystal growth work at the University of Minnesota was supported by DOE-BES Award DE- SC0006858. The work at UBC was supported by the Killam, Alfred P. Sloan, Alexander von Humboldt, and NSERC's Steacie Memorial Fellowships (A.D.), the Canada Research Chairs Program (A.D.), NSERC, CFI, and CIFAR Quantum Materials. D.v.d.M. acknowledges the support of the Swiss National Science Foundation under Grant No. 200020-140761 and MaNEP. The Open Access has been funded by Università Cattolica del Sacro Cuore and Elettra-Sincrotrone Trieste S.C.p.A.

Author contributions

C.G., F.C. and F.P. conceived the project and the time-resolved experiments. C.G. coordinated the research activities with input from all the coauthors, particularly F.C., S.D.C., G.C., U.B., A.D., M.C. The pump-supercontinuum-probe technique at the I-LAMP Labs (Brescia) was designed and developed by C.G., F.B. and G.F. The

pump-supercontinuum- probe technique at the T-REX Labs (Elettra, Trieste) was designed and developed by F.C. and F.P. The time-resolved optical measurements and the data analysis were performed by F.C., S.D.C., G.C., S.P., S.M., N.N. and C.G. The Bi2212 crystals were grown and characterized by H.E., M.G., R.C. and A.D. The Hg1201 crystals were grown and characterized by M.K.C, C.J.D., M.J.V. and M.G. Equilibrium ARPES measurements were performed by R.C. and A.D. Non-equilibrium ARPES measurements were performed by D.vdM. The DMFT calculations were carried out by M.C., who provided input for the theoretical interpretation of the experimental data. The text was drafted by C.G., F.C., M.C. and F.P with major input from S.D.C., G.C., R.C., F.B., G.F., U.B., A.D., D.vdM. and M.G. All authors extensively discussed the results and the interpretation, and revised the manuscript.

Additional information

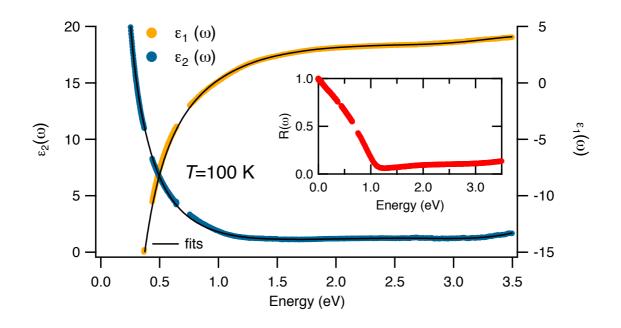
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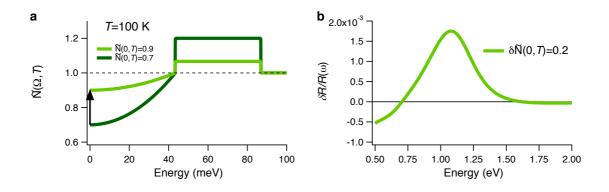
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How to cite this article: Cilento, F. *et al.* Photo-enhanced antinodal conductivity in the pseudogap state of high-Tc cuprates. *Nat. Commun.* 5:4353 doi: 10.1038/ncomms5353 (2014).

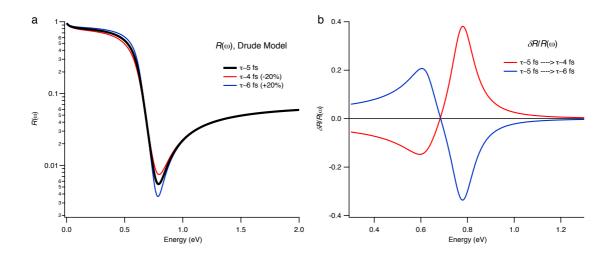
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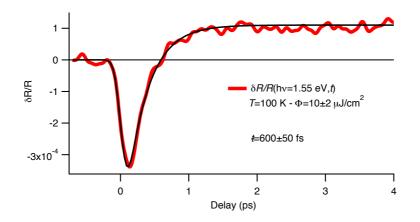
Supplementary Figure 1 | Equilibrium Optical Properties at T=100 K. The real part $(\varepsilon_1(\omega), \text{ right axis})$ and the imaginary part $(\varepsilon_2(\omega), \text{ left axis})$ of the equilibrium dielectric function of the optimally doped Y-Bi2212 sample, measured at T=100 K over a broad energy range, are reported. $R_{eq}(\omega)$ is reported in the inset. The dressed plasma frequency ω_p (defined by $\varepsilon_1(\omega_p)=0$) is 1.15 eV. The black curves are the best Extended Drude Model fits to the data.



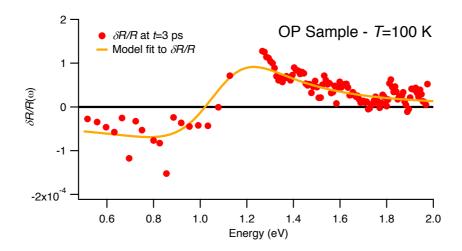
Supplementary Figure 2 | Pseudogap Function and Photoinduced gap filling. a) The pseudogap density of electronic states, $\tilde{N}(\Omega, T)$, obtained by fitting the equilibrium dielectric function at T=100 K (see also Methods), is shown as a dark green line. The transient filling of the pseudogap (light green line) is simulated by increasing the normalized density of states at E_F , i.e., $\tilde{N}(0,T)$. b) The contribution to the $\delta R/R(\omega,t)$, calculated through the differential Extended Drude Model in the case of $\delta \tilde{N}(0,T)=0.2$, is shown.



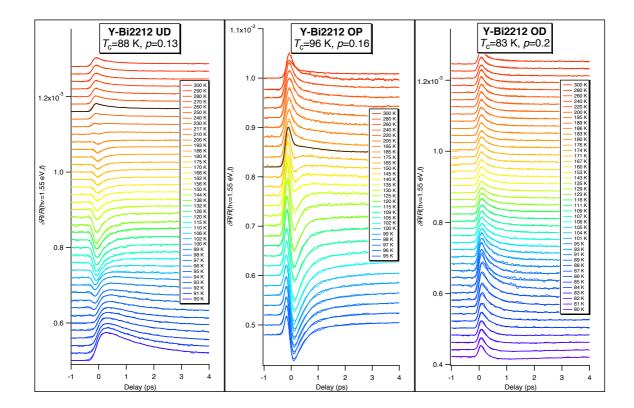
Supplementary Figure 3 | Electronic Scattering Rate and Optical Properties. a. The effect on the Reflectivity $R(\omega)$ of a ±20% modification of the electronic scattering time is shown. The plasma edge narrows (broadens), respectively. b. The same effect is shown in the $\delta R/R(\omega,t)$ signal.



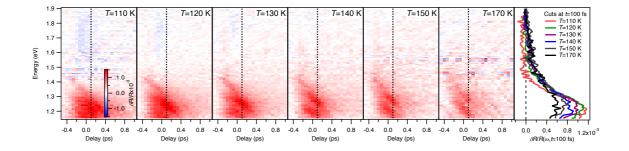
Supplementary Figure 4 | **Decay Time of the Non-Equilibrium Population.** The relaxation time of the $\delta R/R(t)$ signal measured at 100 K, is reported.



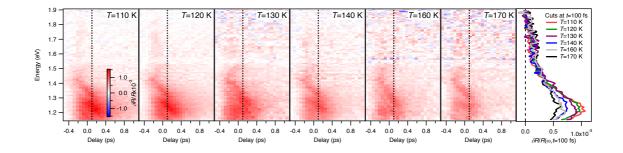
Supplementary Figure 5 | **Long-time reflectivity variation.** The $\delta R/R(\omega,t)$ signal measured at *T*=100 K on OP-YBi2212 is reported (red dots). The yellow line is the best fit to the data obtained by the procedure described in the text.



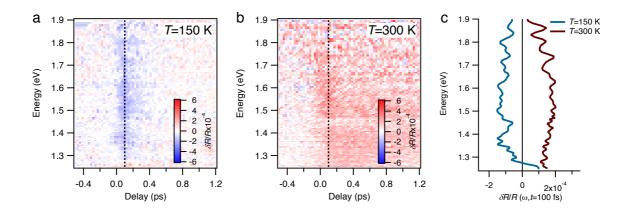
Supplementary Figure 6 | **Single-colour pump-probe measurements.** High-resolution, single-colour (1.55 eV probe photon energy) reflectivity measurements as a function of temperature are reported for three different samples: UD (p=0.13), OP (p=0.16), OD (p=0.2). The results of the fitting procedure are superimposed. Black fits are drawn in correspondence of the temperature below which the finite negative component in f(t) ($I_3 < 0$, see Supplementary Note 6) is observed.



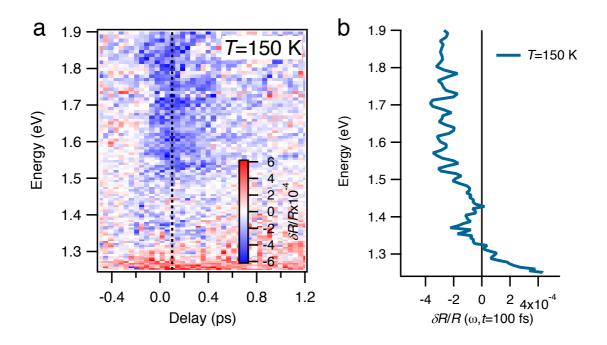
Supplementary Figure 7 | Time-resolved optical spectroscopy on the sOD sample. $\delta R/R(\omega,t)$ on the sOD sample is reported for some selected temperatures. Slices of the $\delta R/R(\omega,t)$ maps at *t*=100 fs are shown on the right panel.



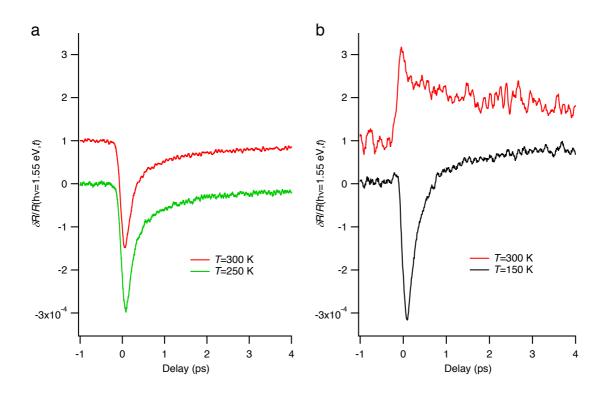
Supplementary Figure 8 | Time-resolved optical spectroscopy on the OD sample. $\delta R/R(\omega,t)$ on the OD sample is reported for some selected temperatures. Slices of the $\delta R/R(\omega,t)$ maps at *t*=100 fs are shown on the right panel.



Supplementary Figure 9 | Time resolved optical spectroscopy on sUD-Hg1201. a. and b. The $\delta R/R(\omega,t)$ data, acquired respectively at T=150 K and T=300 K on the sUD-Hg1201 sample ($T_c=95$ K), are shown. c. The $\delta R/R(\omega)$ slices at t=100 fs are reported.



Supplementary Figure 10 | Time resolved Optical Spectroscopic Measurements on UD Hg1201. a. The $\delta R/R(\omega,t)$ data acquired at T=150 K on the UD Hg1201 sample ($T_c=55$ K) are shown. b. The $\delta R/R(\omega)$ slice at t=100 fs is reported.



Supplementary Figure 11 | **Onset of the Pseudogap for Hg1201. a.** The high-resolution, single colour (1.55 eV probe energy) pump-probe measurements, performed on the UD-Hg1201, are shown. **b.** The same, but for sUD-Hg1201.

The Equilibrium Reflectivity at T=100 K

In Supplementary Fig. 1 we report the real and imaginary parts of the equilibrium dielectric function $\varepsilon_{eq}(\omega)$, measured by conventional reflectivity and ellipsometry techniques (1), in a wide spectral range (0-3.5 eV). The data reported refer to the *ab*-plane pseudo-dielectric function, which has been corrected for the *c*-axis admixture due to the off-normal angle of incidence used with ellipsometry.

A satisfactory fit to the data has been obtained by a model dielectric function containing the Extended Drude term with a non-constant density of states (see Methods) and six Lorentz oscillators (with central energies: 1.53 eV, 1.99 eV, 2.72 eV, 3.85 eV, 4.36 eV and 5.05 eV), accounting for interband and charge transfer optical transitions. In the Extended Drude Model, we consider the same Glue Function $\Pi(\Omega)$ as the one determined from the fitting in the normal state (*T*=300 K) data (see (2)). Assuming Δ_{pg} =40 meV (as determined from STS measurements, see (3)), the best fit to $R_{eq}(\omega)$ provides a value of $\tilde{N}(0, T = 100 \text{ K}) = 0.7 \pm 0.05$, (see Supplementary Note 2) in quantitative agreement with the results reported in (4).

The Non-Constant Density of States and the Photoinduced gap filling

In Supplementary Fig. 2(a) we report (dark green line) the normalized density of states obtained from fitting the Extended Drude Model with a non-constant density of states (see Methods and Supplementary Note 1) to the reflectivity data at equilibrium, reported in Supplementary Fig. 1. The best fit provides $\tilde{N}_{eq}(0,T = 100 \text{ K})=0.7\pm0.05$, when the pseudogap width value is fixed to $\Delta_{pg}=40 \text{ meV}$ (3). After the impulsive pump excitation, a transient gap filling can occur. In Supplementary Fig. 2(b) we report the $\delta R/R(\omega)$ signal arising from a partial filling of the pseudogap, that is accounted for by a partial quench of the density of states, i.e., $\tilde{N}_{neq}(0,T = 100 \text{ K}) - \tilde{N}_{eq}(0,T = 100 \text{ K}) = 0.2 \pm 0.02$.

Isosbestic Points: the link between Electronic Scattering Rate and Optical Properties

In general, the transient variation of the electronic properties after the interaction with the pump pulse, modifies the optical properties over a very broad frequency range. Here we show how broadband time-resolved optical spectroscopy can be used to measure the instantaneous optical scattering rate with 100 fs time resolution. This argument is based on the properties of the so-called '*isosbestic points*' (defined as the crossing frequency (ω) of all the functions $f(\omega,g)$ with different values of the parameter g), discussed in detail in a recent paper (5). In the vicinity of the crossing point, $\partial f/\partial g \simeq 0$ and the function can be expanded with respect to the parameter considered, establishing a simple dependence of $f(\omega,g)$ on the parameter g. As an example, we consider the variation of the scattering rate γ on the prototypical reflectivity $R(\omega)$ of a metal. Within the simple Drude Model, recalling that:

$$R(\omega) = \left| (\sqrt{1 - \varepsilon(\omega)}) / (\sqrt{1 + \varepsilon(\omega)}) \right|^2$$
$$\varepsilon_D(\omega) = \varepsilon_{\inf} - \frac{\omega_p^2}{\omega^2 + i\gamma\omega}$$

the width of the plasma edge is proportional to the scattering rate γ , defined as the inverse of the scattering time τ . This is shown in Supplementary Fig. 3a, where a frequency-independent value $\tau=5$ fs is considered. The values of the other parameters used in the simulation are: $\varepsilon_{inf}=3$, $\omega_p=1.1$ eV, $\gamma=0.12$ eV $\approx(5$ fs)⁻¹. A 20% increase (decrease) of the scattering rate γ results in a broadening (narrowing) of the plasma edge. An isosbestic point (see Supplementary Fig. 3a) is found at the frequency $\tilde{\omega} \sim 0.7$ eV. Close to $\tilde{\omega}$ the reflectivity variation can be expanded as $\delta R(\omega, \gamma)=\partial R/\partial \gamma(\omega)\delta\gamma$, where $\partial R/\partial \gamma > (<)0$ for $\omega > (<) \tilde{\omega}$. Therefore, the effect of a pump-induced modification of the scattering rate can be readily inferred by measuring $\delta R/R(\omega,t)$ over a broad frequency range across $\tilde{\omega}$, as shown in Supplementary Fig 3b.

Relaxation Dynamics in the Pseudogap

The relaxation time of the pump-probe measurements has been determined by fitting a single exponential decay to the pump-probe trace measured at T=100 K on the sUD-YBi2212 sample, excited with a pump fluence equal to $10\pm 2 \ \mu J/cm^2$. The result is reported in Supplementary Fig. 4. A decay time $t=600\pm50$ fs has been obtained. The same decay time has been measured increasing the pump fluence up to $100 \ \mu J/cm^2$.

ps-timescale Reflectivity Variation

The $\delta R/R(\omega,t=3 \text{ ps})$ measured at T=100 K on the OP sample is reported in Supplementary Fig. 5 (red dots). In this case, the measured frequency-dependent reflectivity variation is the opposite than that measured at t=100 fs (see Fig. 3a in the main paper). $\delta R/R(\omega,t=3 \text{ ps})$ can be easily reproduced (yellow line) by assuming $\tilde{N}_{neq}(0,T=100 \text{ K}) - \tilde{N}_{eq}(0,T=100 \text{ K}) \approx 0$ and a relative increase of the scattering rate $\delta \gamma_{\infty}/\gamma_{\infty} \approx 10^{-4}$. The long-time increase of the scattering rate is compatible with a local effective heating of $\delta T=0.6 \text{ K}$, that corresponds to the effective heating estimated considering the pump fluence (10 µJ/cm²) of the experiment and the specific heat of the lattice.

$T^*_{neq}(p)$ from non-equilibrium spectroscopy

The onset temperature T_{neq}^* of the pseudogap, as a function of the hole-doping concentration, has been determined from the analysis of the single-colour (1.55 eV) pump-probe measurements. The appearance in the $\delta R/R(t)$ signal of a negative component with the relaxation time t=600 fs is the consequence of the decrease of the electronic scattering rate as the non-thermal antinodal population is created by the pump pulse. The $\delta R/R(t)$ data at different temperatures and hole-doping concentrations are reported in Supplementary Fig. 6. The function f(t), defined as the sum of three exponentials convoluted with a Gaussian representing the experimental resolution, has been fitted to the data:

$$f(t) = I_1 \cdot e^{-t/\tau_1} + I_2 \cdot e^{-t/\tau_2} + I_3 \cdot e^{-t/\tau_3}$$

The two positive components are needed to reproduce the temporal dynamics in the normal state. They exhibit two distinct decay times: a fast component of ~100 fs (I_1), and a slower one, with a decay time of ~1 ps (I_2). These timescales are related to the coupling of the electrons with two different subsets of phonons, as previously shown (2, 6). The third negative component (I_3) accounts for the transient decrease of the scattering rate in the pseudogap. The temperatures at which a non-zero value of I_3 appears are: $T^*=240$, 165 and 110 K for samples with p=0.13, 0.16 and 0.18, respectively. A zero value of I_3 is obtained at all the temperatures larger than T_c for dopings p>0.18.

The crossing point of $T^*_{neq}(p)$ and the superconducting dome

In this section, we discuss the measurements performed with the time-resolved optical spectroscopy on two overdoped samples: sOD (p=0.18, $T_c=94$ K) and OD (p=0.2, $T_c=83$ K). In the sOD sample, the $\delta R/R(\omega,t=100$ fs) signal above 1.4 eV evolve from positive in the normal state to negative in the pseudogap state at about 100 K (see Supplementary Fig. 7). In the OD sample, the pseudogap-related negative $\delta R/R(\omega,t=100$ fs) signal above 1.4 eV, is never detected for all the temperature larger than T_c (see Supplementary Fig. 8). This result demonstrates that the $T^*_{neq}(p)$ line meets the superconducting dome at a doping concentration of 0.18 .

Measurements on Hg1201

In this section, we discuss the results of time- and frequency-resolved reflectivity measurements on HgBa₂CuO_{4+a} (Hg1201) samples. Supplementary Figures 9 and 10 display the $\delta R/R(\omega,t)$ maps measured on underdoped (UD-Hg1201, $p\approx 0.06$, $T_c=55$ K) and slightlyunderdoped (sUD-Hg2101, $p\approx 0.12$, $T_c=95$ K) Hg1201 crystals. The measurements have been performed in the same experimental conditions as the ones described for Y-Bi2212 samples. The spectral traces taken at t=0 at different temperatures are shown in the panels on the right. The $\delta R/R(\omega,t=100 \text{ fs})$ signal at T=150 K on the sUD-Hg2101 is very similar to the signal measured on underdoped YBi2212 samples. The negative reflectivity variation at photon energies larger than 1.3 eV is the fingerprint of the transient decrease of the scattering rate, related to the pseudogap state. The signal related to the pseudogap gradually disappears as the temperature is increased up to T=300 K. At T=300 K the $\delta R/R(\omega,t=100 \text{ fs})$ is positive for all photon energies and can be reproduced by simply assuming an increase of the scattering rate, in agreement with the results on Y-Bi2212 at T=300 K. On UD-Hg1201 the $\delta R/R(\omega,t=100 \text{ fs})$ signal at T=150 K is very similar and exhibit a negative variation above 1.3 eV at all the temperatures from T_c to 350 K. Supplementary Figure 11 reports the high-resolution, single colour pump-probe measurements performed at different sample temperatures on both the UD and the sUD Hg1201 crystals. In UD-Hg1201 the negative signal characteristic of the pseudogap state persists till the highest temperature is reached (350 K). Further increasing of the temperature leads to a permanent damage of the crystal. This demonstrates that the UD-Hg1021 sample is well within the pseudogap state at T=300 K.

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